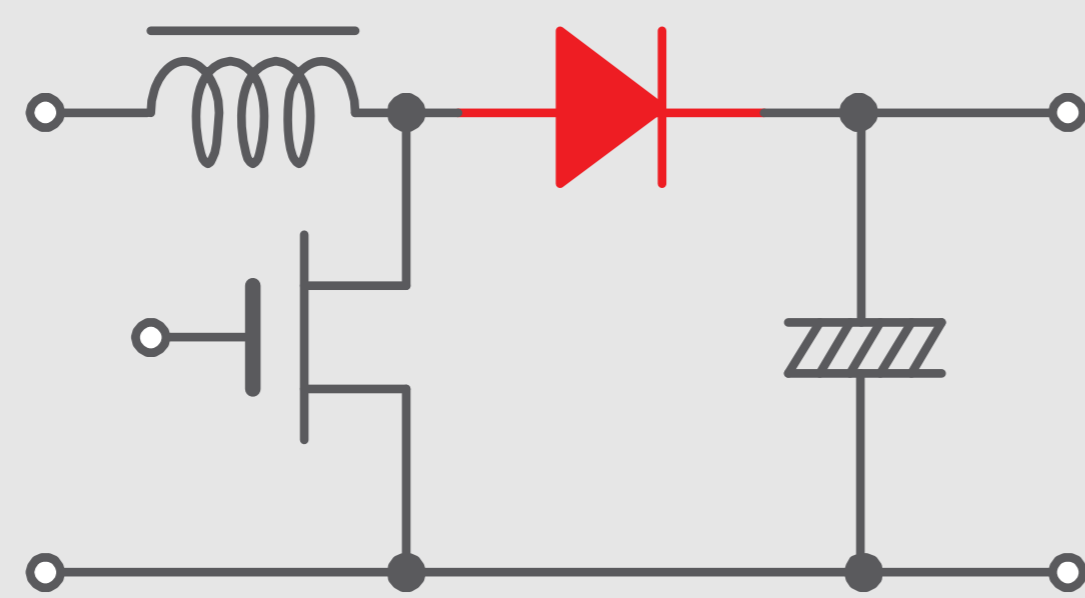


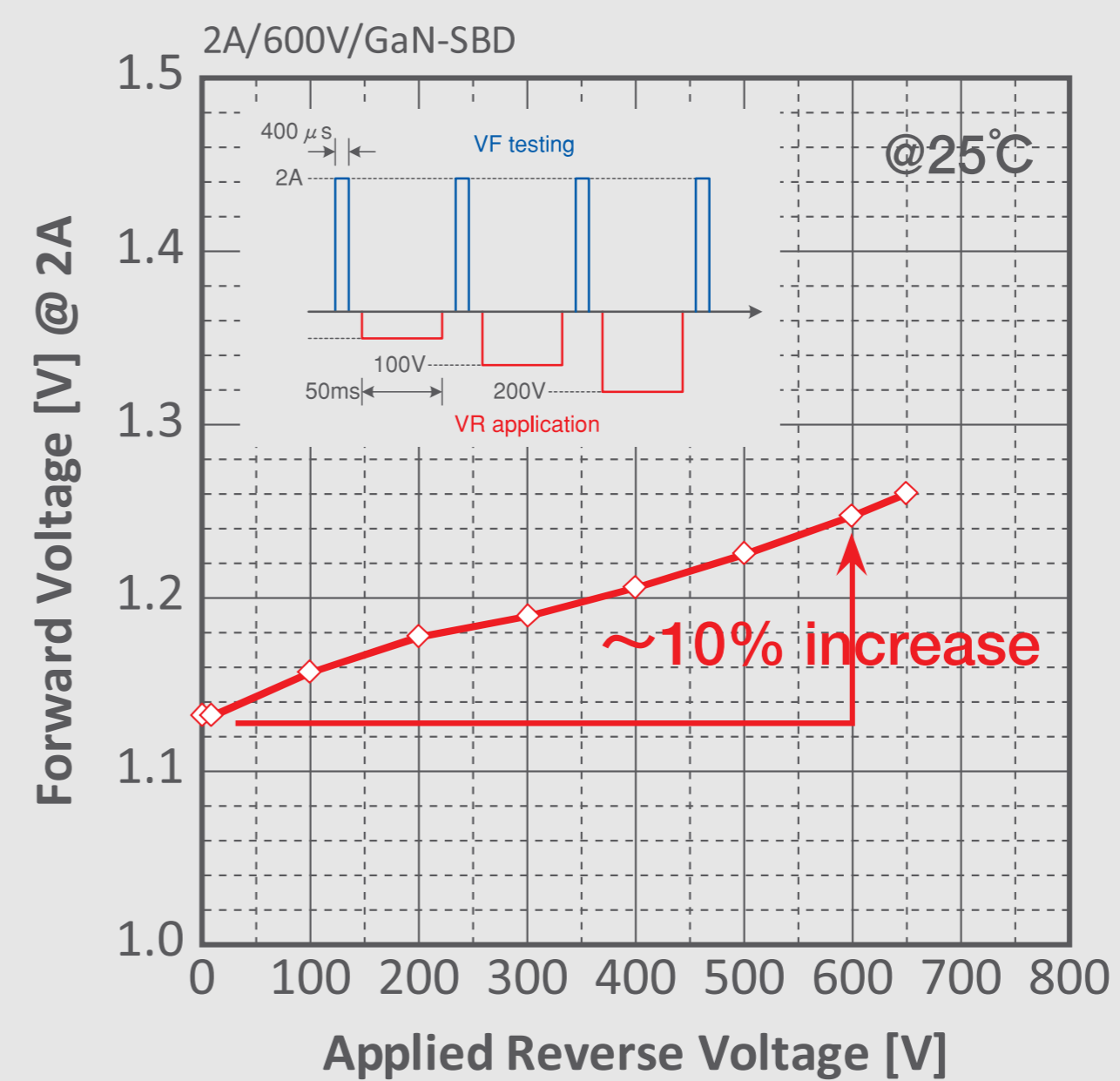


Gallium Nitride 600V SBD



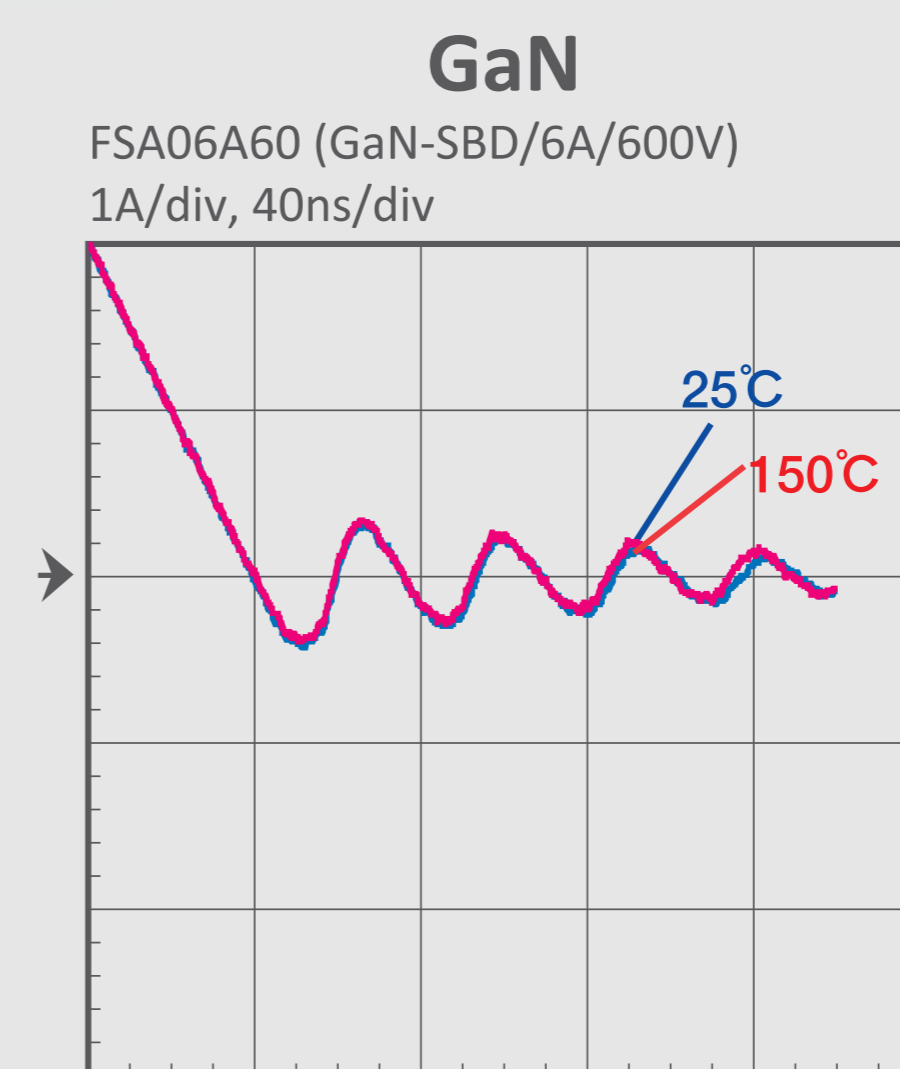
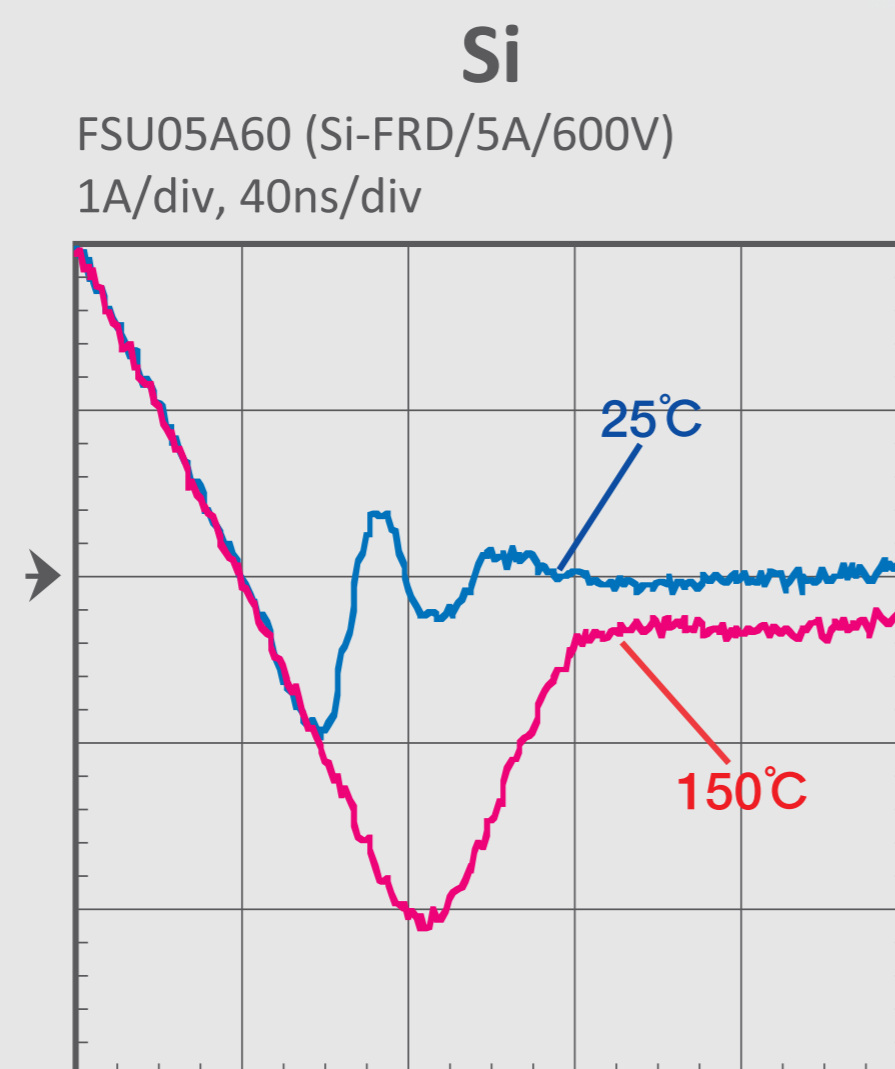
-PFC Circuit

Vr-V Characteristics



-Reduce VF rise due to current collapse to below 20%

Recovery waveform GaN vs Si



Product Line-up

Part Number	PKG	Io[A]	VRRM[V]	Sub.	Sample
FSA04B60	TO-220 (Full-molded)	4	600	Si	Mar., 2013 -
FSA06B60		6	600		